

Enhancement of upconversion emission in Er:LiNbO₃ by codoping with HfO₂ under 1550 nm excitation



Yannan Qian^a, Zhengyu Zhang^a, Xunze Tang^a, Maxim Ivanov^{b, c}, Haiyan Zhang^{a, *}, Qibai Wu^a

^a School of Materials and Energy, Guangdong University of Technology, Guangzhou, 510006, China

^b Institute of Electrophysics of the Ural Branch of Russian Academy of Sciences, Ekaterinburg, 620016, Russia

^c Ural Federal University, Ekaterinburg, 620002, Russia

ARTICLE INFO

Article history:

Received 26 March 2017

Received in revised form

8 May 2017

Accepted 9 May 2017

Keywords:

Lithium niobate

Hafnium and erbium co-doping

Upconversion emission

Solar cells

ABSTRACT

An increased red upconversion emission produced under excitation at 1550 nm was observed in hafnium and erbium co-doped lithium niobate (Hf_(8 mol%)/Er:LiNbO₃), which can be used to increase the photovoltaic efficiency of solar cells. Three 1550 nm photons were required to arouse the green and red emissions in Hf_(x mol%)/Er:LiNbO₃, while the red emitting ⁴F_{9/2} state was populated by a hybrid two- and three-photon process in Hf_(8 mol%)/Er:LiNbO₃. The formation of Er³⁺ cluster sites (Er_{Li}²⁺-Er_{Nb}²⁺) lead to an efficient cross relaxation process ⁴I_{13/2} + ⁴I_{13/2} → ⁴I_{15/2} + ⁴I_{9/2} and enhanced red emission in Hf_(8 mol%)/Er:LiNbO₃.

© 2017 Elsevier B.V. All rights reserved.

1. Introduction

Development of highly efficient photovoltaic solar cells has attracted much research interest for the last years [1]. To reduce a loss of near infrared (NIR) solar radiation, rare earth (RE) ions doped material can be used as a luminescent layer in the solar cells to tune their sensitivity to the solar spectrum [2,3]. Among many RE ions, Er³⁺ ion could be used as a versatile rare earth ion due to its favorable electronic energy level structures, and Er³⁺ ion has two main application fields. The first one is Er³⁺ doped waveguides amplifiers (EDWAs) since the 1.54 μm emission arising from the ⁴I_{13/2} → ⁴I_{15/2} transition of Er³⁺ ion matches well with the third fiber-optics communication window [4,5]. The second one is photovoltaic, since the ⁴I_{15/2} → ⁴I_{13/2} transition could efficiently up-convert 1550 nm NIR light into visible emissions absorbed by the solar cells. A. Shalav reported [6] that the responsivity of bifacial silicon solar cell is increased in NIR range due to NaYF₄:Er phosphors attached. The peak external quantum efficiency is 2.5 ± 0.2% in the silicon solar cell under laser excitation at 1523 nm, and the corresponding internal quantum efficiency is 3.8%. Pursuing the

same goal G. Y. Chen demonstrated the intense visible and NIR upconversion (UC) photoluminescence in LiYF₄:Er nanocrystals under excitation at 1490 nm [7]. R. M. Rodríguez has converted successfully the infrared (IR) light into UC emission in Er³⁺-doped Gd₂O₃S, which could enhance the photovoltaic efficiency of solar cells [8].

Recently, particular attention has been given to LiNbO₃ as an excellent host material for RE ion doping. Limitation of highest phonon energy (about 880 cm⁻¹) of LiNbO₃ decreases nonradiative relaxation rates according to Miyakawa-Dexter theory [9]. Previous works reported that the anti-photorefractive ions such as Mg²⁺, Zn²⁺, In³⁺ and Zr⁴⁺ not only suppress the optical damage of LiNbO₃ but also affect the optical characteristics of the material doped with RE ions [10–13]. L. Sun found that under 980 nm excitation, the heavily doping with MgO enhanced the 1.5 μm emission, while reduced the green UC emission in Er:LiNbO₃ [10]. It has been reported by J.W. Shur that UC emission in Zr/Tm:LiNbO₃ is about three times higher than that in Zn/Tm:LiNbO₃ under 980 nm excitation [13]. For the last years, extensive studies on the holographic properties and the high resistance against ultraviolet photorefractive of hafnium and erbium co-doped lithium niobate (Hf/Er:LiNbO₃) crystal have appeared [14]. And it also has been found that Hf/Er-codoped SiO₂ planar waveguide is a viable system for 1.5 μm application [15]. However, there are few reports on

* Corresponding author.

E-mail addresses: hyzhang@gdut.edu.cn, wangrui001@hit.edu.cn (H. Zhang).

converting 1550 nm light into visible UC emission in Hf/Er:LiNbO₃. Therefore, the upconversion emission of Er³⁺ ions induced by excitation at 1550 nm in Hf/Er:LiNbO₃ are essential to study to increase the solar cells efficiency.

In this work, the UC luminescence of Hf/Er:LiNbO₃ co-doped crystals with different concentration of Hf⁴⁺ and Er³⁺ ions grown by Czochralski technique is investigated in detail and discussed. The pump dependence analyses and UC mechanisms are proposed under 1550 nm excitation. The ultraviolet (UV)-visible spectra of Hf/Er:LiNbO₃ are discussed.

2. Experimental

Congruent (Li/Nb \approx 48.6/51.4) Er (1 mol%):LiNbO₃ crystals codoped with x mol% Hf⁴⁺ ions (x = 0, 2, 4, 6 and 8) are grown along the ferroelectric c axis by Czochralski technique. The purities of raw materials (Li₂CO₃, Nb₂O₅, HfO₂ and Er₂O₃) are 99.99%. The detailed growth process can be described as follows: The raw materials of Li₂CO₃, Nb₂O₅, HfO₂ and Er₂O₃ were mixed for 24 h, and then were heated at 750 °C and 1150 °C, respectively, for 2 h to remove CO₂ and to form polycrystalline powder. The optimum growth conditions were depicted as follows: an axial temperature gradient of 40 ~ 50 K/cm, the rotating rate of 10 ~ 25 rpm, and the pulling rate of 0.5 ~ 2 mm/h. The grown crystals were polarized at 1200 °C with a current density of 5 mA/cm². The boules were cut into Y-cut plates ($X \times Y \times Z$ = 10 × 2 × 10 mm³) with polished surfaces. The grown five crystals are named as Er-0.0, Hf/Er-2.0/1.0 Hf/Er-4.0/1.0 Hf/Er-6.0/1.0 and Hf/Er-8.0/1.0, respectively. The UC emission spectra excited by the 1550 nm distributed feed back (DFB) laser (ADFB-PU-1550-33-R-FA, Amonics Inc., Hongkong) are recorded by the combined fluorescence lifetime and steady state spectrometer (FLS920, Edinburgh Inc., U.K.). The UV-visible diffuse reflectance spectra of the powders were measured with a UV-vis spectrophotometer (UV9000, Shanghai Metash Instruments Co. LTD, China).

3. Results and discussion

The UC emission spectra of the Hf/Er:LiNbO₃ crystals under 1550 nm excitation are shown in Fig. 1. The weak green emissions centered at 525/550 nm and an intense red UC emission at 675 nm are attributed to the transitions of Er³⁺ ion: $^2H_{11/2}$, $^4S_{3/2} \rightarrow ^4I_{15/2}$ and $^4F_{9/2} \rightarrow ^4I_{15/2}$, respectively [16,17]. In comparison with Er:LiNbO₃ the intensity of the green and red UC emissions is lower in Hf _{x} (x = 2, 4, 6 mol%)/Er:LiNbO₃, while remarkably higher at the Hf⁴⁺

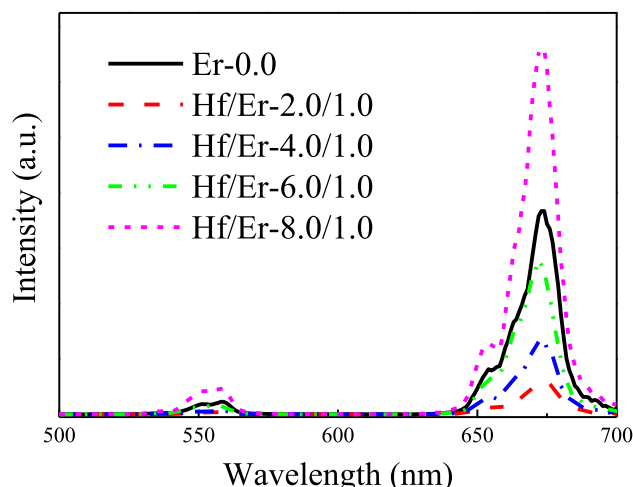


Fig. 1. The UC emission spectra of Hf/Er:LiNbO₃ under 1550 nm excitation.

concentration of 8 mol%. In all of the samples doped with Hf⁴⁺ ions, the intensity increases with the Hf⁴⁺ concentration increased. It is well known that the intensity of luminescence is direct related to the local environment, the dopant concentration and the distribution of active ions in a host material. Here, as for the same Er³⁺ content, there should be a constant value for the green and red UC emissions. Therefore, the behavior that the changed intensities of UC emissions are regardless of the Er³⁺ content implies the local environment of Er³⁺ ion is tailored by Hf⁴⁺ ions under 1550 nm excitation.

To understand the UC mechanisms, Fig. 2 illustrates a double-logarithmic plot of fluorescence intensity as a function of pump power of 1550 nm excitation. For an unsaturated UC process, the number of photons required to populate the upper emitting state can be obtained by the relation: $I_f \propto P^n$ [18,19], where P is the pump power intensity, I_f is the fluorescence intensity, and n is the number of the 0.8 eV photons (1550 nm laser wavelength) required to induce the green and red UC emissions. As shown in Fig. 2, slopes of the green and red UC emissions are 3.12 and 3.09 for Hf/Er-2.0/1.0, 3.13 and 3.06 for Hf/Er-4.0/1.0, 3.05 and 2.79 for Hf/Er-6.0/1.0, respectively, indicating the three-photon process needed to populate the green and red UC emissions in Hf _{x} (x = 2, 4, 6 mol%)/Er:LiNbO₃ under 1550 nm excitation. The n value of 2.88 suggests the green UC emission is populated by a three-photon process in Hf/Er-8.0/1.0. The fact that the n value of 2.52 for the red UC emission is less than the expected n = 3 implies that a two-photon process is involved to induce the red UC emission besides a three-photon process in Hf/Er-8.0/1.0.

Fig. 3 displays the energy levels of Er³⁺ ion as well as the proposed UC mechanisms under 1550 nm excitation. As for the three-photon process to populate the green and red UC emissions, Er³⁺ ions at the ground $^4I_{15/2}$ state absorb three 1550 nm photons and get excited to the upper $^2H_{11/2}$ state through the ground state absorption (GSA: $^4I_{15/2} + 0.8$ eV (6451 cm⁻¹) photon \rightarrow $^4I_{13/2}$) and excited state absorption (ESA1: $^4I_{13/2} + 0.8$ eV photon \rightarrow $^4I_{9/2}$) and ESA3 ($^4I_{9/2} + 0.8$ eV photon \rightarrow $^2H_{11/2}$). The red emitting $^4F_{9/2}$ state is populated via GSA, ESA1 and ESA2 ($^4I_{11/2} + 0.8$ eV photon \rightarrow $^4F_{9/2}$). According to n = 2.52, the two-photon process to populate the red UC emission in Hf/Er-8.0/1.0 can be described as follows: after the GSA process, the cross relaxation (CR) process of $^4I_{13/2} + ^4I_{13/2} \rightarrow ^4I_{9/2} + ^4I_{15/2}$, substituting for one-photon process of ESA1,

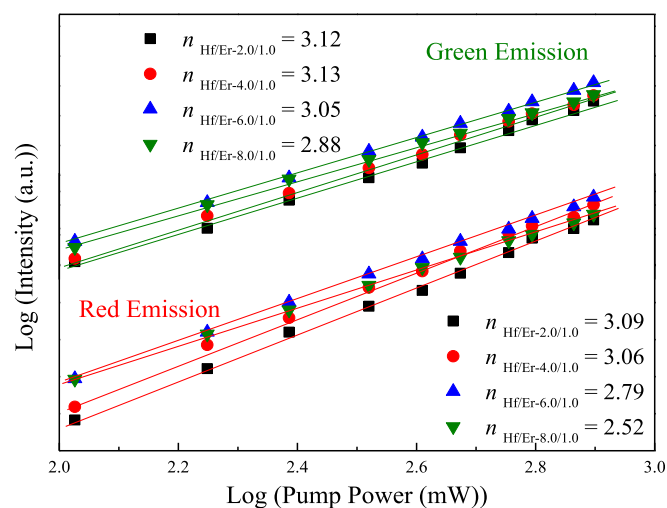


Fig. 2. A double-logarithmic plot of power dependence of green and red UC emission intensities for Hf/Er:LiNbO₃ under 1550 nm excitation. (For interpretation of the references to colour in this figure legend, the reader is referred to the web version of this article.)

Download English Version:

<https://daneshyari.com/en/article/5442581>

Download Persian Version:

<https://daneshyari.com/article/5442581>

[Daneshyari.com](https://daneshyari.com)